# Transition Edge Sensor Modeling

Following "Transition-Edge Sensors, K.D. Irwin and G. C. Hilton"

# **TESS** operation

- Set a **voltage** across the TES (V<sub>TES</sub>)
- Put TES in series with an inductor
- Current in TES  $\rightarrow$  magnetic flux in inductor
- $\bullet \quad \rightarrow \text{SQUID measures magnetic flux}$
- $\rightarrow$  SQUID measures current I<sub>TES</sub>
- Calculate TES resistance with  $V_{TES}/I_{TES}$







#### **Differential equations**

$$L\frac{\mathrm{d}I}{\mathrm{d}t} = V - IR_L - IR(T,I)$$

$$C\frac{\mathrm{d}T}{\mathrm{d}t} = -P_{\mathrm{bath}} + P_{\mathrm{J}} + P$$

$$P_{\text{bath}} = K \left( T^n - T^n_{\text{bath}} \right)$$



# Quiescent solution and Electro-thermal stability

- Typical scenario:
  - Tb ~ 10 mK
  - T<sub>TES</sub> (critical temperature Tc) ~ 50 mK
- Joule heating keeps TES at elevated temperature
   P = V<sup>2</sup>/R
- In Quiescence, TES operates at
  - $\circ$  T<sub>0</sub>: Operating temperature, close to Tc
  - $\circ$  R<sub>0</sub>: TES operating resistance
    - ~30% of Rn (normal Resistance)
  - $P_0$ : "Bias power", power to heat TES from Tb to T0
- When particle hit  $\rightarrow$  TES heats up  $\rightarrow$  R goes up
  - $\rightarrow$  P decreases  $\rightarrow$  TES cools back down







# More "random" definitions (aka jargons)

Constant temperature dynamic resistance 

ce 
$$R_{\rm dyn} \equiv \left. \frac{\partial V}{\partial I} \right|_{T_0} = R_0 \left( 1 + \beta_I \right)$$

$$\tau \equiv \frac{C}{G}$$

 $\tau_I =$ 

Natural thermal time constant 

Low frequency loop gain with constant current 

$$\mathscr{L}_I \equiv \frac{P_{J_0} \alpha_I}{GT_0}$$

- Electrical time constant
- Current biased thermal time constant

$$\tau_{\rm el} = \frac{L}{R_L + R_0 (1 + \beta_I)} = \frac{L}{R_L + R_{\rm dyn}}$$
$$\tau_I = \frac{\tau}{1 - \mathscr{L}_I}$$
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#### Linearized differential equation

$$L\frac{\mathrm{d}I}{\mathrm{d}t} = V - IR_L - IR(T, I)$$
$$C\frac{\mathrm{d}T}{\mathrm{d}t} = -P_{\mathrm{bath}} + P_{\mathrm{J}} + P$$

• Small signal limit, Taylor expansion, neglecting all higher order terms

$$\frac{\mathrm{d}\delta I}{\mathrm{d}t} = -\frac{R_L + R_0 \left(1 + \beta_I\right)}{L} \delta I - \frac{\mathscr{L}_I G}{I_0 L} \delta T + \frac{\delta V}{L}$$
$$\frac{\mathrm{d}\delta T}{\mathrm{d}t} = \frac{I_0 R_0 \left(2 + \beta_I\right)}{C} \delta I - \frac{\left(1 - \mathscr{L}_I\right)}{\tau} \delta T + \frac{\delta P}{C}.$$

δV and δP are small perturbations around bias voltage V and input power P
 Put in for later analyses, eg. particle power injection, noise

#### Matrix differential equation

$$\frac{\mathrm{d}}{\mathrm{d}t} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} = - \begin{pmatrix} \frac{1}{\tau_{\mathrm{el}}} & \frac{\mathscr{L}_I G}{I_0 L} \\ -\frac{I_0 R_0 \left(2 + \beta_I\right)}{C} & \frac{1}{\tau_I} \end{pmatrix} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} + \begin{pmatrix} \frac{\delta V}{L} \\ \frac{\delta P}{C} \end{pmatrix}$$

- Solve for homogeneous equations first  $\rightarrow$  setting  $\delta V$  and  $\delta P$  to 0
- Diagonalize the matrix  $\rightarrow$  two eigenvalues with two eigenvectors

$$\frac{d}{dt}f_{\pm}(t) = -\lambda_{\pm}f_{\pm}(t)$$

# Differential equation solution $\begin{bmatrix} \frac{\mathrm{d}}{\mathrm{d}t} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} = -\begin{pmatrix} \frac{1}{\tau_{\mathrm{el}}} & \frac{\mathscr{L}_I G}{I_0 L} \\ -\frac{I_0 R_0 (2 + \beta_I)}{C} & \frac{1}{\tau_I} \end{pmatrix} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} + \begin{pmatrix} \frac{\delta V}{L} \\ \frac{\delta P}{C} \end{pmatrix} \\ \frac{\mathrm{d}}{\mathrm{d}t} f_{\pm}(t) = -\lambda_{\pm} f_{\pm}(t)$

- Solve for homogeneous equations first  $\rightarrow$  setting  $\delta V$  and  $\delta P$  to 0
- Diagonalize the matrix  $\rightarrow$  two eigenvalues with two eigenvectors

$$\begin{pmatrix} \delta I \\ \delta T \end{pmatrix} = A_{+}e^{-\lambda_{+}t} \overrightarrow{v_{+}} + A_{-}e^{-\lambda_{-}t} \overrightarrow{v_{-}}$$
$$\frac{1}{\tau_{\pm}} \equiv \lambda_{\pm} = \frac{1}{2\tau_{\rm el}} + \frac{1}{2\tau_{I}} \pm \frac{1}{2}\sqrt{\left(\frac{1}{\tau_{\rm el}} - \frac{1}{\tau_{I}}\right)^{2} - 4\frac{R_{0}}{L}\frac{\mathscr{L}_{I}(2+\beta_{I})}{\tau}}{\tau}}$$
$$\overrightarrow{v_{\pm}} = \begin{pmatrix} \frac{1-\mathscr{L}_{I} - \lambda_{\pm}\tau}{2+\beta_{I}} \frac{G}{I_{0}R_{0}}}{1} \end{pmatrix}$$

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#### Specific solution 1 -- Impulse energy input

• Particle incident and instantaneously thermalization

 $\delta T(0) = \delta T = E/C \qquad \qquad \delta I(0) = 0$ 

• Solve for A±, then...

$$\delta I(t) = \left(\frac{\tau_I}{\tau_+} - 1\right) \left(\frac{\tau_I}{\tau_-} - 1\right) \frac{1}{(2+\beta_I)} \frac{C\delta T}{I_0 R_0 \tau_I^2} \frac{\left(e^{-t/\tau_+} - e^{-t/\tau_-}\right)}{(1/\tau_+ - 1/\tau_-)}$$
$$\delta T(t) = \left(\left(\frac{1}{\tau_I} - \frac{1}{\tau_+}\right) e^{-t/\tau_-} + \left(\frac{1}{\tau_I} - \frac{1}{\tau_-}\right) e^{-t/\tau_+}\right) \frac{\delta T}{(1/\tau_+ - 1/\tau_-)}$$

•  $\tau$ +,  $\tau$ - : "rise time" and "fall time" of a pulse with impulse energy deposition

# Specific solution 1 -- Impulse energy input

• When L (inductance) is small,  $\tau + << \tau$ -

$$\tau_+ \to \tau_{\rm el},$$

$$\tau_{-} \rightarrow \tau \frac{1 + \beta_{I} + R_{L}/R_{0}}{1 + \beta_{I} + R_{L}/R_{0} + (1 - R_{L}/R_{0})\mathscr{L}_{I}} = \tau_{\text{eff}}$$
$$\mathscr{L}_{I} \equiv \frac{P_{J_{0}}\alpha_{I}}{GT_{0}}$$

- Recall from last lecture, when  $R_L/R_0 << 1$ , "Stiff voltage bias limit"
- $\beta_1 \rightarrow 0$  (not modelled in last lecture)

$$au_{
m eff} = rac{ au_0}{1 + rac{lpha P_0}{T_0 G}} = rac{ au_0}{1 + rac{lpha}{n} (1 - \left(rac{T_b}{T_0}
ight)^n)}$$

# Specific solution 2 -- small sinusoidal power input $\delta P = \operatorname{Re}(\delta P_0 e^{i\omega t})$

• Useful to derive responsivity

$$\frac{d}{dt} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} = - \begin{pmatrix} \frac{1}{\tau_{\rm el}} & \frac{\mathscr{L}_I G}{I_0 L} \\ \frac{-I_0 R_0 (2 + \beta_I)}{C} & \frac{1}{\tau_I} \end{pmatrix} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} + \begin{pmatrix} 0 \\ \frac{\delta P_0}{C} \end{pmatrix} e^{i\omega t}$$

• After some math.....

$$\frac{dI}{dP}(\omega) = s_I(\omega) = -\frac{1}{I_0R_0} \frac{1}{(2+\beta_I)} \underbrace{\frac{(1-\tau_+/\tau_I)}{(1+i\omega\tau_+)} \underbrace{(1-\tau_-/\tau_I)}_{(1+i\omega\tau_-)}}_{(1+i\omega\tau_+)} \underbrace{\frac{dT}{dP}(\omega)}_{(1+i\omega\tau_+)} = s_T(\omega) = \frac{1}{G} \frac{\tau_+\tau_-}{\tau^2} \frac{(\tau/\tau_+ + \tau/\tau_- + \mathscr{L}_I - 1 + i\omega\tau_-)}{(1+i\omega\tau_+)(1+i\omega\tau_-)}.$$

- Two low-pass filters
  - For a review of one-pole filter and its response in Laplace domain, see eg. <u>https://www.embeddedrelated.com/showarticle/590.php</u>

#### Complex impedance

- Impedance of the system in a complex plane, as a function of frequency
  - Given Voltage excitation of  $\omega$  angular frequency, what's current and phase?

$$\frac{\mathrm{d}}{\mathrm{d}t} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} = - \begin{pmatrix} \frac{1}{\tau_{\mathrm{el}}} & \frac{\mathscr{L}_I G}{I_0 L} \\ -\frac{I_0 R_0 \left(2 + \beta_I\right)}{C} & \frac{1}{\tau_I} \end{pmatrix} \begin{pmatrix} \delta I \\ \delta T \end{pmatrix} + \begin{pmatrix} \frac{\delta V}{L} \\ \frac{\delta P}{C} \end{pmatrix} \qquad \text{Voltage excitation} \\ \text{of } V \omega \\ \text{Fourier} \\ \text{Transform} \qquad \begin{pmatrix} \frac{1}{\tau_{\mathrm{el}}} + i\omega & \frac{\mathscr{L}_I G}{I_0 L} \\ -\frac{I_0 R_0 (2 + \beta_I)}{C} & \frac{1}{\tau_I} + i\omega \end{pmatrix} \begin{pmatrix} I_\omega \\ T_\omega \end{pmatrix} = \begin{pmatrix} \frac{V_\omega}{L} \\ 0 \end{pmatrix}$$

# Complex

Complex impedance  

$$\begin{pmatrix} \frac{1}{\tau_{el}} + i\omega & \frac{\mathscr{L}_{IG}}{I_{0L}} \\ \frac{-I_{0}R_{0}(2+\beta_{I})}{C} & \frac{1}{\tau_{I}} + i\omega \end{pmatrix} \begin{pmatrix} I_{\omega} \\ T_{\omega} \end{pmatrix} = \begin{pmatrix} \frac{V_{\omega}}{L} \\ 0 \end{pmatrix}$$

$$Z_{\omega} = V_{\omega}/I_{\omega} = R_{L} + i\omega L + Z_{TES}$$

$$Z_{TES} = R_{0}(1+\beta_{I}) + \frac{R_{0}\mathscr{L}_{I}}{1-\mathscr{L}_{I}} \frac{2+\beta_{I}}{1+i\omega\tau_{I}}$$
Or.. complex admittance Y=1/Z
$$Y(\omega) = s_{I}(\omega)I_{0} \frac{\mathscr{L}_{I} - 1}{\mathscr{L}_{I}} (1+i\omega\tau_{I})$$

$$P_{0} = S_{I}(\omega)I_{0} \frac{\mathscr{L}_{I} - 1}{\mathscr{L}_{I}} (1+i\omega\tau_{I})$$

#### Complex impedance used to extract TES parameters

• Often takes data at different Tb and different R0



# **TES Stability**

- For a TES to be stable:
  - $\tau \pm$  need to be **real (not oscillating)**
  - $Re(\tau \pm)$  need to be **positive (converging back to quiescence)**

$$\frac{1}{\tau_{\pm}} \equiv \lambda_{\pm} = \frac{1}{2\tau_{\mathrm{el}}} + \frac{1}{2\tau_{I}} \pm \frac{1}{2} \sqrt{\left(\frac{1}{\tau_{\mathrm{el}}} - \frac{1}{\tau_{I}}\right)^{2} - 4\frac{R_{0}}{L}\frac{\mathscr{L}_{I}(2+\beta_{I})}{\tau}}{R_{0}}$$
$$R_{0} > \frac{(\mathscr{L}_{I} - 1)}{(\mathscr{L}_{I} + 1 + \beta_{I})}R_{L}$$

- In large  $L_1$  limit (large amplification),  $R_0 > R_L$
- If Re(τ±) is positive, but τ± isn't real → TES is underdamped (oscillate) but will converge → Electrothermal oscillation
- If  $\text{Re}(\tau \pm)$  is negative  $\rightarrow$  thermal runaway

https://arxiv.org/pdf/2304.14926.pdf

#### Complex detector modeling





$$\begin{split} L\frac{dI}{dt} = &I_0 * R_0 - I * R_{tes} & \text{Doug Pinckney, undergrad honor thesis} \\ C_a \frac{dT_a}{dt} = &\frac{E}{c\sqrt{2\pi}} e^{\frac{-(t-t_0)^2}{2c^2}} - K_{a,b}(T_a^{n_{a,b}} - T_b^{n_{a,b}}) - K_{a,auq}(T_a^{n_{a,au1}} - T_{au1}^{n_{a,au1}}) - K_{a,g}(T_a^{n_{a,g}} - T_g^{n_{a,g}}) \\ C_{aul}\frac{dT_{au1}}{dt} = &K_{a,aul}(T_{au1}^{n_{a,au1}} - T_a^{n_{a,au1}}) - K_{au1,wb1}(T_{au1}^{n_{au1,wb1}} - T_{wb1}^{n_{au1,wb1}}) \\ C_g \frac{dT_g}{dt} = &K_{a,g}(T_g^{n_{a,g}} - T_a^{n_{a,g}}) - K_{g,si}(T_g^{n_{g,si}} - T_{si}^{n_{g,si}}) \\ C_{wb1}\frac{dT_{wb1}}{dt} = &K_{au1,wb1}(T_{wb1}^{m_{au1,wb1}} - T_{au1}^{n_{au1,wb1}}) - K_{wb1,au2}(T_{wb1}^{n_{wb1,au2}} - T_{au2}^{n_{wb1,au2}}) \\ C_{au2}\frac{dT_{au2}}{dt} = &K_{si,au2}(T_{au2}^{n_{si,au2}} - T_{si}^{n_{si,au2}}) - K_{wb1,au2}(T_{au2}^{n_{wb1,au2}} - T_{wb1}^{n_{wb1,au2}}) - K_{au2,tes}(T_{au2}^{n_{au2,tes}} - T_{tes}^{n_{au2,tes}}) \\ C_{si}\frac{dT_{si}}{dt} = &K_{g,si}(T_{si}^{n_{g,si}} - T_{g}^{n_{g,si}}) - K_{si,au2}(T_{si}^{n_{si,au2}} - T_{au2}^{n_{si,au2}}) - K_{si,tes}(T_{si}^{n_{si,tes}} - T_{tes}^{n_{si,tes}}) \\ - K_{si,m}(T_{si}^{n_{si,m}} - T_{m}^{n_{si,m}}) \\ C_{tes}\frac{dT_{tes}}{dt} = &I^2 R_{tes} - K_{au2,tes}(T_{tes}^{n_{au2,tes}} - T_{au2}^{n_{au2,tes}}) - K_{si,tes}(T_{tes}^{n_{si,tes}} - T_{si}^{n_{si,tes}}) - K_{tes,m}(T_{tes}^{n_{tes,m}} - T_{m}^{n_{tes,m}}) \\ C_{m}\frac{dT_{m}}{dt} = &K_{tes,m}(T_{mes,m}^{n_{tes,m}} - T_{tes}^{n_{tes,m}}) - K_{si,m}(T_{m}^{n_{si,m}} - T_{si}^{n_{si,m}}) - K_{m,wb2}(T_{wb2}^{n_{m,wb2}} - T_{wb2}^{n_{m,wb2}}) \\ C_{wb2}\frac{dT_{wb2}}{dt} = &K_{m,wb2}(T_{wb2}^{n_{m,wb2}} - T_{m}^{n_{m,wb2}}) - K_{wb2,b}(T_{wb2}^{n_{wb2}} - T_{b}^{n_{wb2,b}}) \\ \end{bmatrix}$$

#### Differential equation $\rightarrow$ Matrices (time, frequency)



#### One note about noise and resolution

- With responsivity s<sub>1</sub>, can derive theoretical resolution:
  - Model various noise
    - Johnson noise, thermal fluctuation noise, etc.
  - Convert to "Noise Equivalent Power"

$$\Delta E_{\rm rms} = \left( \sqrt{\int_0^\infty \frac{4\,df}{{\rm NEP}(f)^2}} \right)^{-1}$$

• Irwin's derivation shows

$$\Delta E_{\rm rms} = \sqrt{4k_{\rm B}T^2 C \frac{1}{\alpha} \sqrt{\frac{n}{2}}}$$

• Will come back to this next class